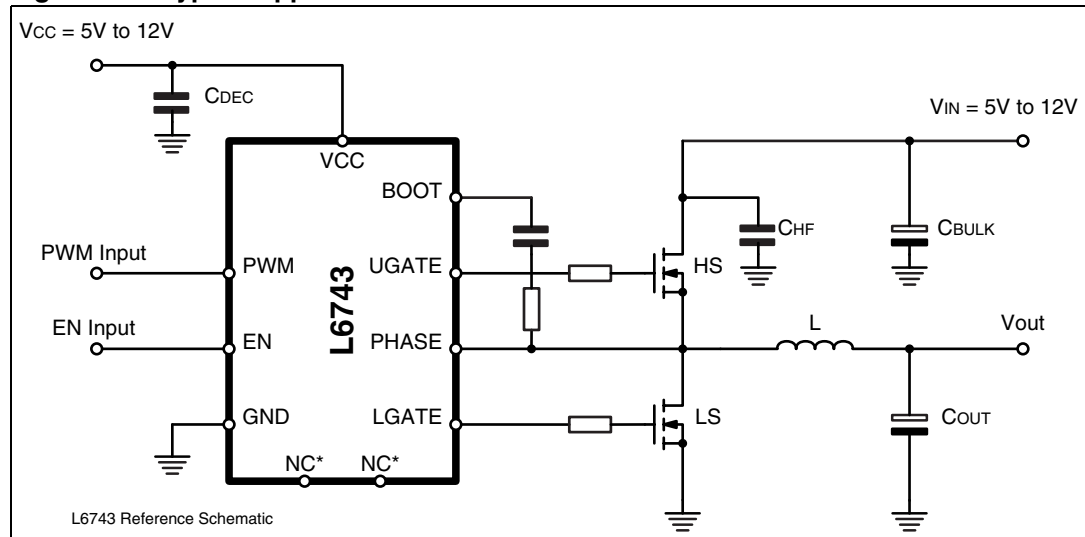


# 1 Typical application circuit and block diagram

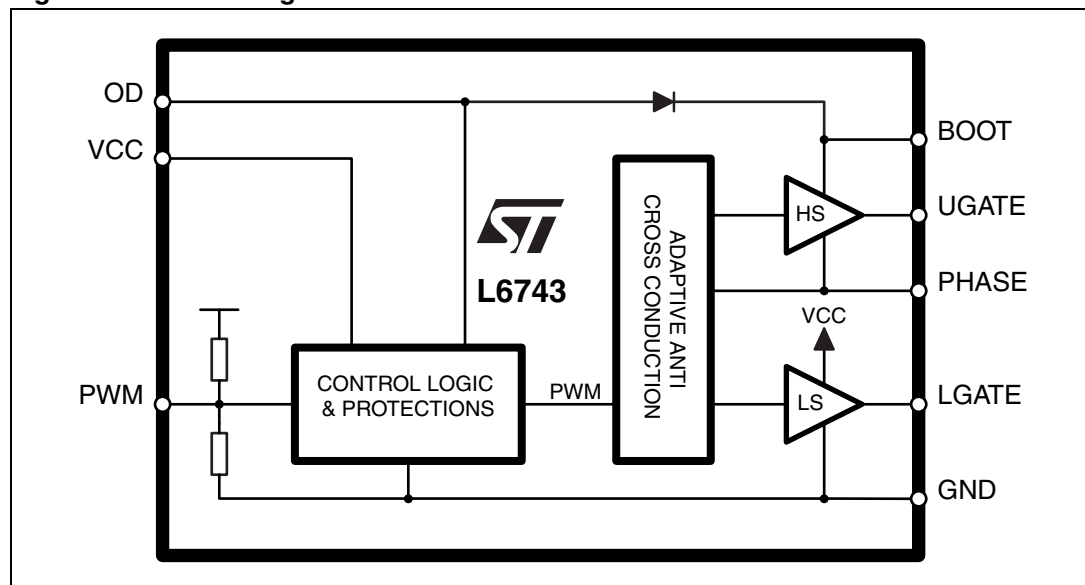
## 1.1 Application circuit

Figure 1. Typical application circuit



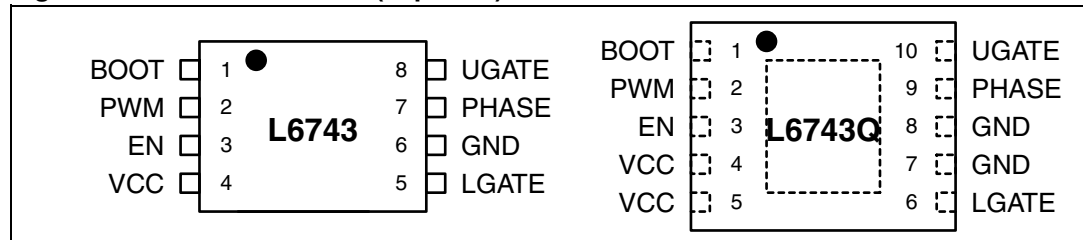
## 1.2 Block diagram

Figure 2. Block diagram



## 2 Pins description and connection diagrams

Figure 3. Pins connection (Top view)



### 2.1 Pin description

Table 2. Pins descriptions

| Pin # |       | Name    | Function                                                                                                                                                                                                                                                                                                                |
|-------|-------|---------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SO8   | DFN10 |         |                                                                                                                                                                                                                                                                                                                         |
| 1     | 1     | BOOT    | High-Side Driver Supply.<br>This pin supplies the High-Side floating driver. Connect through a $R_{BOOT}$ - $C_{BOOT}$ capacitor to the PHASE pin.<br>Internally connected to the cathode of the integrated Bootstrap diode.                                                                                            |
| 2     | 2     | PWM     | Control input for the driver, 5V compatible.<br>This pin controls the state of the driver and which external MOSFET have to be turned-ON according to EN status. If left floating and in conjunction with EN asserted, it causes the driver to enter the High-Impedance (HiZ) state which causes all MOSFETs to be OFF. |
| 3     | 3     | EN      | Enable Input for the Driver.<br>Pull High to enable the driver according to the PWM status. If pulled low will cause the drive to enter HiZ state with all MOSFET OFF regardless of the PWM status.                                                                                                                     |
| 4, 5  | 4     | VCC     | Device and LS Driver power supply. Connect to any voltage between 5V and 12V. Bypass with low-ESR MLCC capacitor to GND.                                                                                                                                                                                                |
| 6     | 5     | LGATE   | Low-Side Driver Output.<br>Connect directly to the Low-Side MOSFET gate. A small series resistor can be useful to reduce dissipated power especially in high frequency applications.                                                                                                                                    |
| 7, 8  | 6     | GND     | All internal references, logic and drivers are referenced to this pin. Connect to the PCB ground plane.                                                                                                                                                                                                                 |
| 9     | 7     | PHASE   | High-Side Driver return Path. Connect to the High-Side MOSFET Source.<br>This pin is also monitored for the adaptive dead-time management and Pre-OV Protection.                                                                                                                                                        |
| 10    | 8     | UGATE   | High-Side Driver Output.<br>Connect to High-Side MOSFET gate.                                                                                                                                                                                                                                                           |
| PAD   | -     | TH. PAD | Thermal pad connects the Silicon substrate and makes good thermal contact with the PCB. Connect to the PGND plane. (DFN10 only)                                                                                                                                                                                         |

### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com)

**Table 3. SO8 Mechanical data**

| Dim.             | mm.                  |      |      | inch  |       |       |
|------------------|----------------------|------|------|-------|-------|-------|
|                  | Min                  | Typ  | Max  | Min   | Typ   | Max   |
| A                | 1.35                 |      | 1.75 | 0.053 |       | 0.069 |
| A1               | 0.10                 |      | 0.25 | 0.004 |       | 0.010 |
| A2               | 1.10                 |      | 1.65 | 0.043 |       | 0.065 |
| B                | 0.33                 |      | 0.51 | 0.013 |       | 0.020 |
| C                | 0.19                 |      | 0.25 | 0.007 |       | 0.010 |
| D <sup>(1)</sup> | 4.80                 |      | 5.00 | 0.189 |       | 0.197 |
| E                | 3.80                 |      | 4.00 | 0.15  |       | 0.157 |
| e                |                      | 1.27 |      |       | 0.050 |       |
| H                | 5.80                 |      | 6.20 | 0.228 |       | 0.244 |
| h                | 0.25                 |      | 0.50 | 0.010 |       | 0.020 |
| L                | 0.40                 |      | 1.27 | 0.016 |       | 0.050 |
| k                | 0° (min.), 8° (max.) |      |      |       |       |       |
| ddd              |                      |      | 0.10 |       |       | 0.004 |

1. Dimensions D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15mm (.006inch) in total (both side).

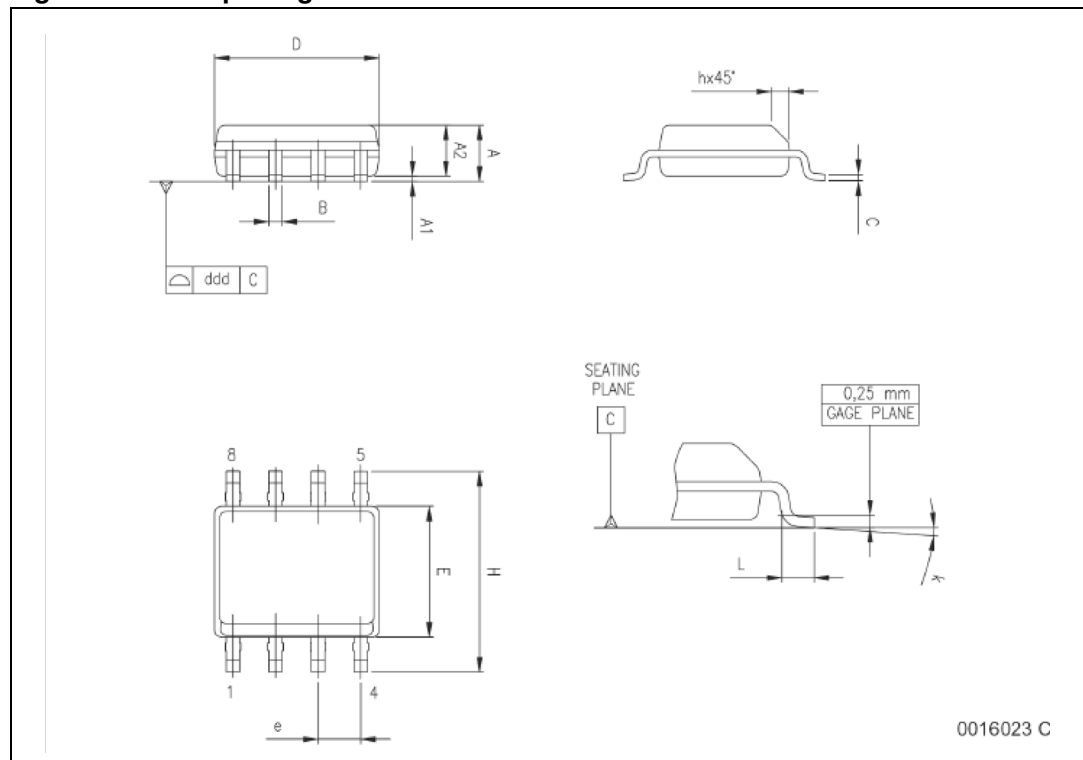
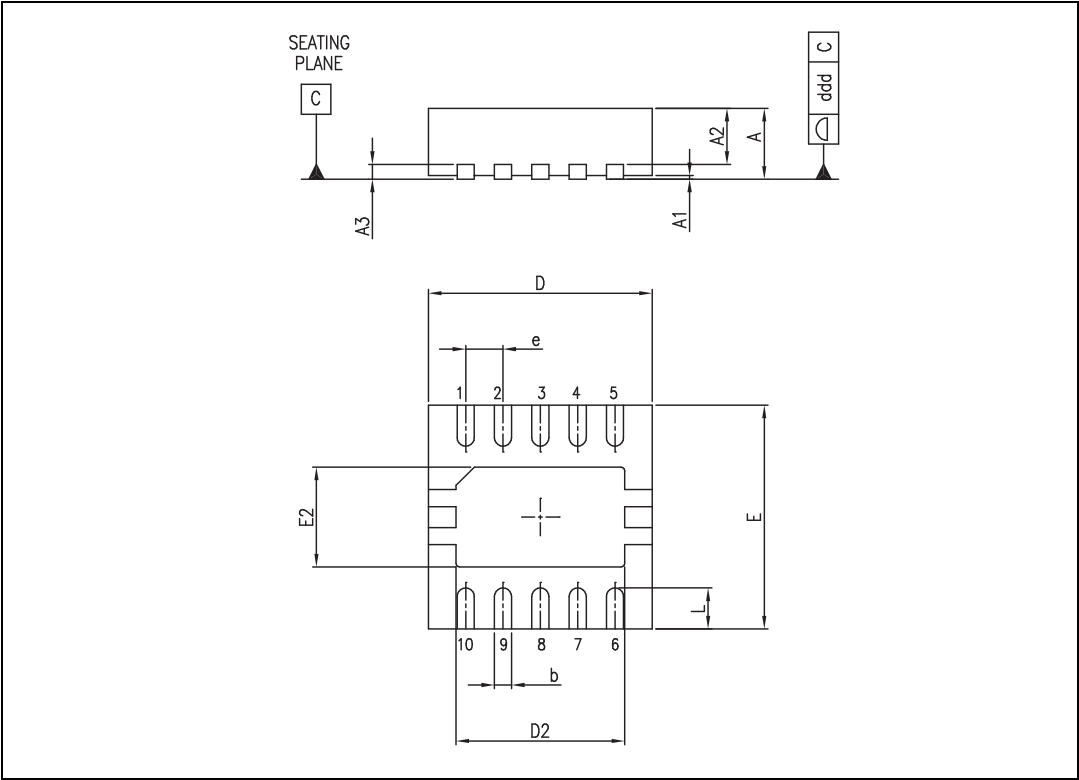
**Figure 4. SO8 package dimensions**

Table 4. DFN10 mechanical data

| Ref. | mm   |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | Min. | Typ. | Max. | Min.  | Typ.  | Max.  |
| A    | 0.80 | 0.90 | 1.00 | 0.031 | 0.035 | 0.039 |
| A1   |      | 0.02 | 0.05 |       | 0.001 | 0.002 |
| A2   |      | 0.70 |      |       | 0.028 |       |
| A3   |      | 0.20 |      |       | 0.008 |       |
| b    | 0.18 | 0.23 | 0.30 | 0.007 | 0.009 | 0.012 |
| D    |      | 3.00 |      |       | 0.118 |       |
| D2   | 2.21 | 2.26 | 2.31 | 0.087 | 0.089 | 0.091 |
| E    |      | 3.00 |      |       | 0.118 |       |
| E2   | 1.49 | 1.64 | 1.74 | 0.059 | 0.065 | 0.069 |
| e    |      | 0.50 |      |       | 0.20  |       |
| L    | 0.3  | 0.4  | 0.5  | 0.012 | 0.016 | 0.020 |

Figure 5. Package dimensions



## 4 Revision history

**Table 5. Document revision history**

| Date        | Revision | Changes          |
|-------------|----------|------------------|
| 30-Mar-2007 | 1        | Initial release. |

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